	Type	Hits	Search Text	DBs
1	BRS	2176	inductive adj load and (FET MOSFET MOS (field adj effect))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	820	inductive adj load same (FET MOSFET MOS (field adj effect))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	43	inductive adj load same (FET MOSFET MOS (field adj effect)) and switch near gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	3	inductive adj load same (FET MOSFET MOS (field adj effect)) and switch near gate near ground	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	11	inductive adj load same (FET MOSFET MOS (field adj effect)) and switch same gate near ground	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	16	("3979607" | "5023692" | "5028811" | "5079608" | "5115369" | "5162966" | "5264736" | "5401996" | "5764088" | "5812006" | "5828244" | "5875089" | "5963066" | "6127746" | "6201427" | "6204715").PN.	USPAT
7	BRS	1	inductive adj load same igbt and switch same gate near ground	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BRS	1	"5500616".PN.	USPAT
9	BRS	3	5500616.URPN.	USPAT
10	BRS	4	inductive adj load same igbt and switch same gate near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	BRS	0	inductive adj load same (FET MOSFET MOS (field adj effect)) and chrage adj pump	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	BRS	46	inductive adj load same (FET MOSFET MOS (field adj effect)) and charge adj pump	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
13	BRS	4	inductive adj load same (FET MOSFET MOS (field adj effect)) and charge adj pump and gate near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	BRS	778	361/91.1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
15	BRS	8	5,828,244	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
1	2004/09/21 13:10			0
2	2004/09/20 15:13			0
3	2004/09/20 15:14			0
4	2004/09/20 15:58			0
5	2004/09/20 16:18			0
6	2004/09/20 15:26			0
7	2004/09/20 15:51			0
8	2004/09/20 15:49			0
9	2004/09/20 15:49			0
10	2004/09/20 15:52			0
11	2004/09/20 15:59			0
12	2004/09/20 15:59			0
13	2004/09/20 16:00			0
14	2004/09/20 16:19			0
15	2004/09/21 15:24			0

	Type	Hits	Search Text	DBs
16	BRS	7	("3742252" | "4481434" | "4631652" | "4777387" | "5126651" | "5352932" | "5371418").PN.	USPAT
17	BRS	0	esd same (FET MOS MOSFET) same gate near drain near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
18	BRS	205	esd same (FET MOS MOSFET) same gate same drain same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
19	BRS	299	transient same (FET MOS MOSFET) same gate same drain same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
20	BRS	1	transient same (FET MOS MOSFET) same gate same drain near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
21	BRS	34	transient same (FET MOS MOSFET) same gate near drain same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
22	BRS	7	("3742252" | "4481434" | "4631652" | "4777387" | "5126651" | "5352932" | "5371418").PN.	USPAT
23	BRS	11	("4356416" | "4459498" | "4500801" | "4677325" | "4716309" | "4719531" | "4737667" | "4816699" | "4859875" | "4928053" | "4952827").PN.	USPAT
24	BRS	6	5828244.URPN.	USPAT
25	BRS	126	esd and trigger adj circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
26	BRS	82	esd same trigger adj circuit	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
27	BRS	0	esd same trigger adj circuit near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
28	BRS	30	esd same trigger adj circuit same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
29	BRS	436556	MOS MOSFET FET and bias adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
30	BRS	2193	(MOS MOSFET FET) and bias adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
31	BRS	837	(MOS MOSFET FET) same bias adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
16	2004/09/21 13:12			0
17	2004/09/21 13:15			0
18	2004/09/21 13:29			0
19	2004/09/21 13:30			0
20	2004/09/21 13:30			0
21	2004/09/21 13:31			0
22	2004/09/21 13:49			0
23	2004/09/21 13:51			0
24	2004/09/21 13:53			0
25	2004/09/21 13:54			0
26	2004/09/21 13:55			0
27	2004/09/21 13:55			0
28	2004/09/21 13:57			0
29	2004/09/21 13:58			0
30	2004/09/21 13:58			0
31	2004/09/21 13:58			0
	Time Stamp	Comments	Error Definition	Errors

	Type	Hits	Search Text	DBs
32	BRS	38	(MOS MOSFET FET) same bias adj resistor same gate near drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
33	BRS	0	(MOS MOSFET FET) same miller adj effect near resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
34	BRS	41	(MOS MOSFET FET) same miller adj effect same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
35	BRS	5	("4916599" | "5457624" | "5552695" | "5847554" | "6304474").PN.	USPAT
36	BRS	3144	361/111	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
37	BRS	1245	361/91.5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
32	2004/09/21 13:59			0
33	2004/09/21 14:00			0
34	2004/09/21 14:00			0
35	2004/09/21 14:07			0
36	2004/09/21 16:04			0
37	2004/09/22 09:27			0